捷多邦,专业PCB打样工厂,24小时加急出货 查询BCR25KM-12LB供应商 RENESA BCR25KM-12LB Triac Medium Power Use REJ03G1676-0100 Rev.1.00 Jun 05, 2008 WWW.DZS **Features** I_{T (RMS)}: 25 A Insulated Type • V_{DRM}: 600 V Planar Type I_{FGTI}, I_{RGTI}, I_{RGTIII}: 50 mA V_{iso}: 2000 V **Outline** RENESAS Package code: PRSS0003AB-A (Package name: TO-220FN) T₁ Terminal
 T₂ Terminal 3. Gate Terminal 3 Applications

Contactless AC switch, electric heater control, light dimmer, on/off and speed control of small induction motor, on/off control of copier lamp

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
	Oymbol	12		
Repetitive peak off-state voltage Note1	V _{DRM}	600	V	
Non-repetitive peak off-state voltage Note1	V _{DSM}	720	V	

Notes: 1. Gate open.



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Parameter	Symbol	Ratings	Unit	Conditions		
RMS on-state current	I _{T (RMS)}	25	A	Commercial frequency, sine full wave 360° conduction, Tc = 62°C		
Surge on-state current	I _{TSM}	250	A	50 Hz sinewave 1 full cycle, peak value, non-repetitive		
I ² t for fusion	l ² t	313	A ² s	Value corresponding to 1 cycle of half wave 50Hz, surge on-state current		
Peak gate power dissipation	P _{GM}	5	W			
Average gate power dissipation	P _{G (AV)}	0.5	W			
Peak gate voltage	V _{GM}	10	V			
Peak gate current	I _{GM}	2	А			
Junction Temperature	Tj	-40 to +150	°C			
Storage temperature	Tstg	-40 to +150	°C			
Mass	_	2.0	g	Typical value		
Isolation voltage	V _{iso}	2000	V	Ta = 25°C, AC 1 minute,		
				$T_1 \bullet T_2 \bullet G$ terminal to case		

Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}	—	_	3.0/5.0	mA	Tj = $125/150^{\circ}$ C, V _{DRM} applied
On-state voltage		V _{TM}	—	_	1.5	V	$Tc = 25^{\circ}C$, $I_{TM} = 40$ A, instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	V_{FGTI}	—	_	2.0	V	$Tj = 25^{\circ}C, V_{D} = 6 V, R_{L} = 6 \Omega,$
	II	V _{rgti}	—	_	2.0	V	R _G = 330 Ω
	III	V _{RGTIII}	—	_	2.0	V	
Gate trigger curent ^{Note2}	Ι	I _{FGTI}	—	_	50	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	I _{RGTI}	—	_	50	mA	R _G = 330 Ω
	III	I _{RGTIII}	—		50	mA	
Gate non-trigger voltage		V_{GD}	0.2/0.1	_	_	V	$Tj = 125/150^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	—	_	2.8	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state commutation voltage ^{Note4}		(dv/dt)c	10/1	_	—	V/µs	Tj = 125/150°C

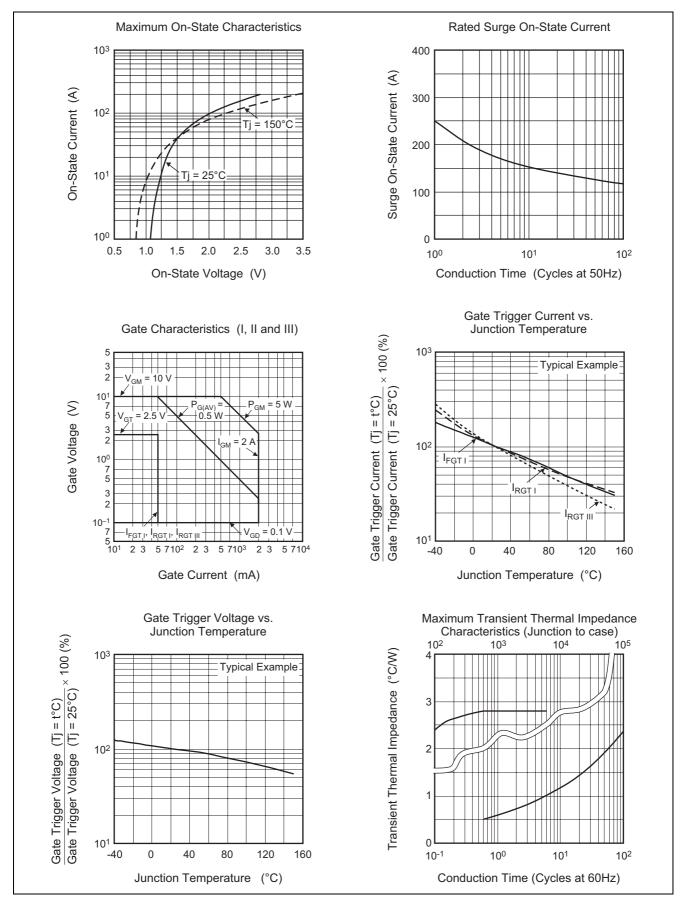
Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

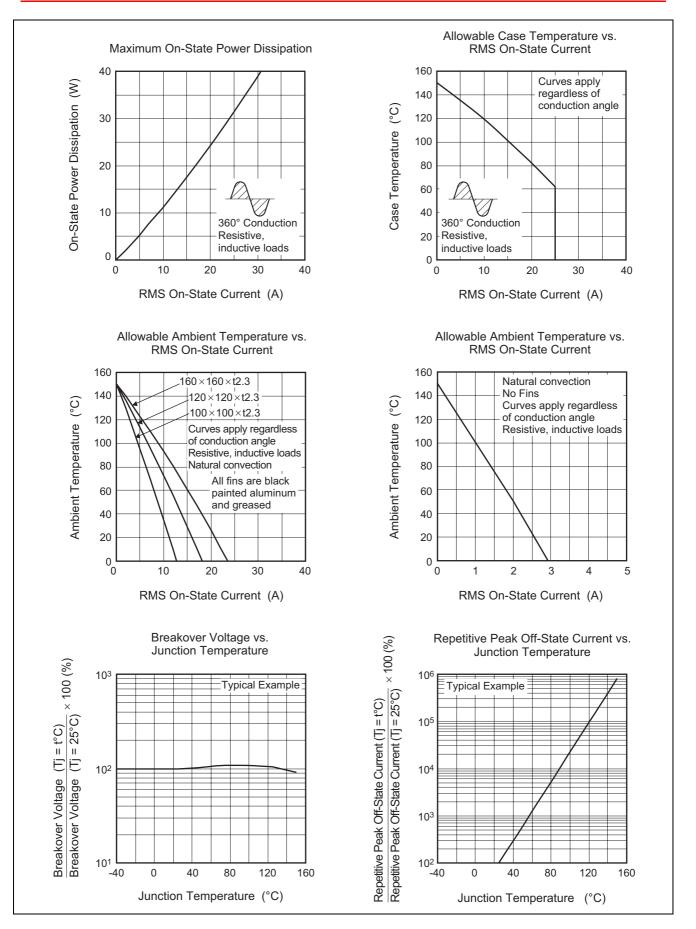
3. The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 0.5°C/W.

4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

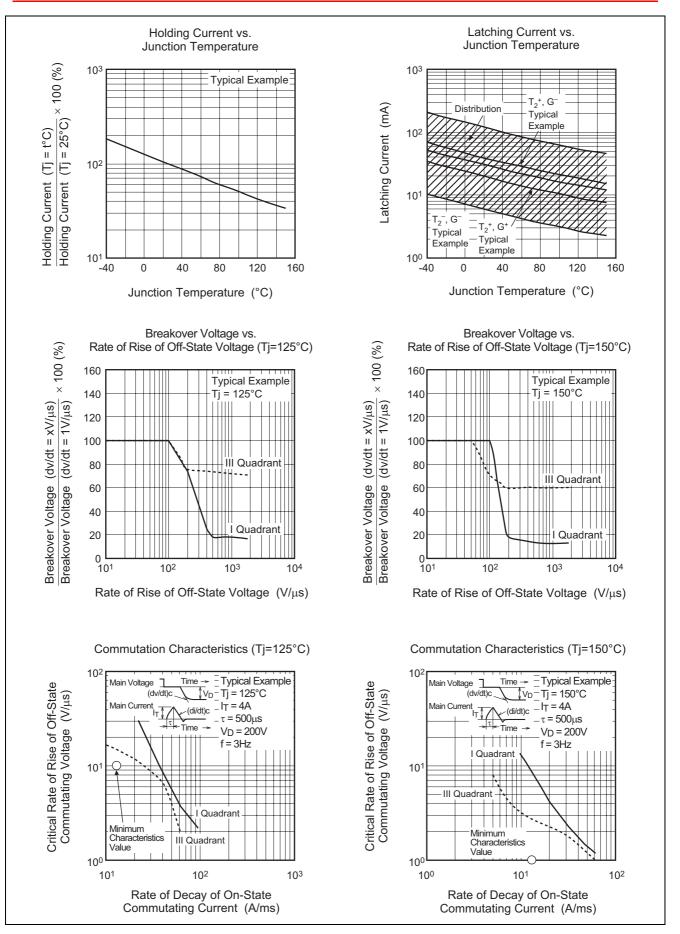
Test conditions	Commutating voltage and current waveforms (inductive load)		
1. Junction temperature Tj = 125/150°C	Supply Voltage → Time		
 Rate of decay of on-state commutating current (di/dt)c = -13 A/ms 	Main Current → Time		
3. Peak off-state voltage V _D = 400 V	Main VoltageTime (dv/dt)cV		

Performance Curves

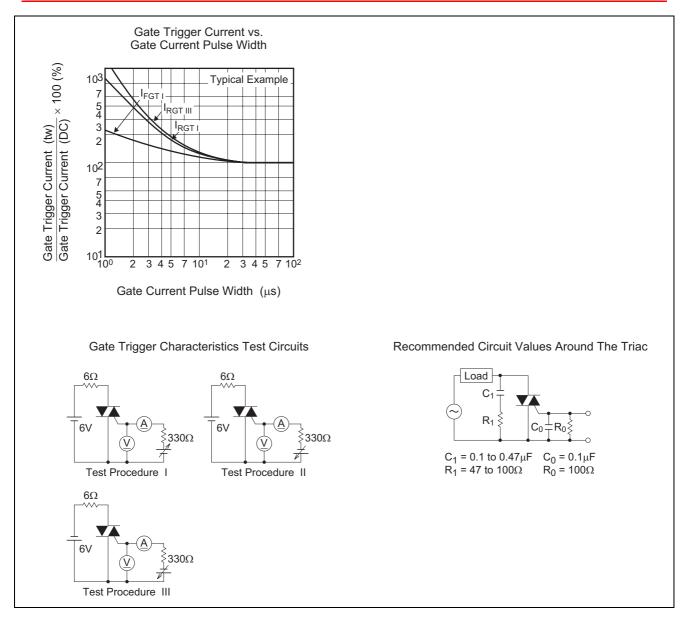




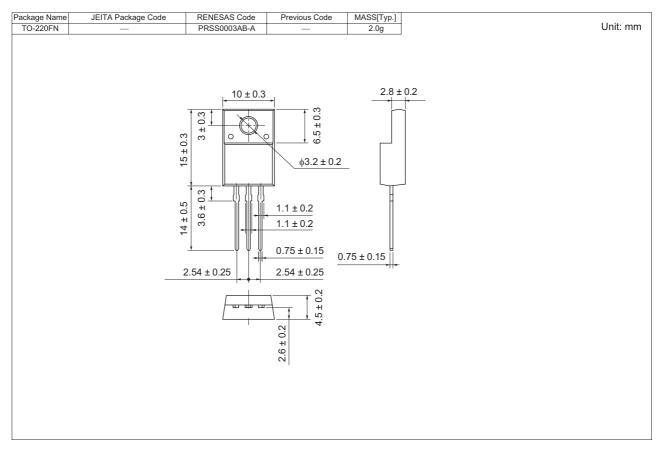
BCR25KM-12LB



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Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Plastic Magazine (Tube)	50	Type name	BCR25KM-12LB
Lead form	Plastic Magazine (Tube)	50	Type name – Lead forming code	BCR25KM-12LB -A8

Note : Please confirm the specification about the shipping in detail.

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